











DRV3204E-Q1

SLVSCB5B-OCTOBER 2013-REVISED JULY 2016

DRV3204E-Q1 Three-Phase Brushless Motor Driver

Not Recommended for New Designs

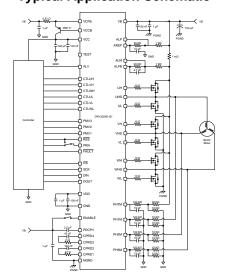
1 Features

- Qualified for Automotive Applications
- AEC Q100 Qualified with the Following Results:
 - Device Temperature Grade 0: -40°C to 150°C
 Ambient Operating Temperature Range
 - Device HBM ESD Classification Level H2
 - Device CDM ESD Classification Level C2
- 3-Phase Pre-Drivers for N-Channel MOS Field-Effect Transistors (MOSFETs)
- Pulse-Width Modulation (PWM) Frequency up to 20 kHz
- Fault Diagnostics
- Charge Pump
- Phase Comparators
- · Microcontroller (MCU) Reset Generator
- Serial Port I/F (SPI)
- Motor-Current Sense
- 5-V Regulator
- Low-Current Sleep Mode
- Operation VB Range From 5.3 V to 26.5 V
- 48-Pin PHP

2 Applications

- Automotive Motor-Control Applications
 - Oil Pump
 - Fuel Pump
 - Water Pump

Typical Application Schematic



3 Description

The DRV3204E-Q1 device is a field-effect transistor (FET) pre-driver designed for three-phase motor control for applications such as an oil pump or a water pump. The device has three high-side pre-FET drivers and three low-side drivers which are under the control of an external MCU. A charge pump supplies the power for the high side, and there is no requirement for а bootstrap capacitor. commutation, this integrated circuit (IC) sends a conditional motor signal and output to the MCU. Diagnostics provide undervoltage, overvoltage, overcurrent, overtemperature and power-bridge faults. The motor current is measured using an integrated current-sense amplifier and comparator in a battery common-mode range, which allows the use of the motor current in a high-side current-sense application. External resistors set the gain. The predrivers and other internal settings are configured through the SPI.

Device Information⁽¹⁾

| PART NUMBER | PACKAGE | BODY SIZE (NOM) |
|-------------|------------|-------------------|
| DRV3204E-Q1 | HTQFP (48) | 7.00 mm × 7.00 mm |

(1) For all available packages, see the orderable addendum at the end of the datasheet.

DRV3204E-Q1

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4 Revision History

Changes from Bayleian A / January 2014) to Bayleian B

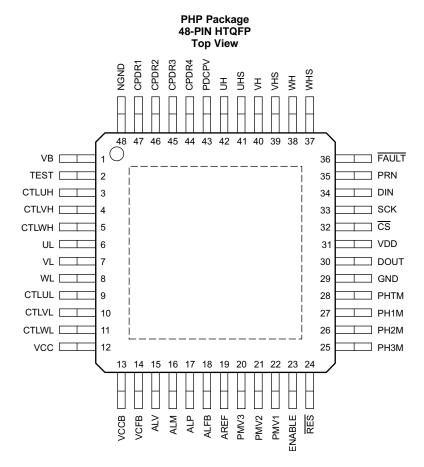
NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

| • | Shanges from Revision A (January 2014) to Revision B | Page |
|---|---|------|
| • | Added Pin Configuration and Functions section, ESD Ratings table, Feature Description section, Application and Implementation section, Device and Documentation Support section, and Mechanical, Packaging, and Orderable Information section | 1 |
| • | Changed device status to NRND. | 1 |

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5 Pin Configuration and Functions



Pin Functions

| PIN | | | | FIII FUIICUOIIS | |
|-------|-----|------|-------------------|--|--|
| NAME | NO. | TYPE | MAXIMUM RATING | DESCRIPTION | |
| ALFB | 18 | 0 | -0.3 V to 40 V | Motor current-sense amplifier feedback | |
| ALM | 16 | I | -0.3 V to 40 V | Motor current-sense amplifier negative input | |
| ALP | 17 | I | -0.3 V to 40 V | Motor current-sense amplifier positive input | |
| ALV | 15 | 0 | -0.3 V to 6 V | Motor current-sense amplifier output | |
| AREF | 19 | 0 | -0.3 V to 40 V | Reference output of motor current- sense amplifier | |
| CPDR1 | 47 | 0 | -0.3 V to 40 V | Charge-pump output | |
| CPDR2 | 46 | 0 | -0.3 V to 40 V | Charge-pump output | |
| CPDR3 | 45 | 0 | -0.3 V to 40 V | 0 V Charge-pump output | |
| CPDR4 | 44 | 0 | -0.3 V to 40 V | | |
| CS | 32 | I | -0.3 V to 6 V | SPI chip select | |
| CTLUH | 3 | I | -0.3 V to 6 V | Pre-driver parallel input | |
| CTLUL | 9 | I | -0.3 V to 6 V | Pre-driver parallel input | |
| CTLVH | 4 | I | -0.3 V to 6 V | Pre-driver parallel input | |
| CTLVL | 10 | I | –0.3 V to 6 V | Pre-driver parallel input | |
| CTLWH | 5 | I | -0.3 V to 6 V | Pre-driver parallel input | |
| CTLWL | 11 | I | -0.3 V to 6 V | Pre-driver parallel input | |
| DIN | 34 | I . | -0.3 V to 6 V | SPI data input | |
| DOUT | 30 | 0 | –0.3 V to 6 V | SPI data output | |



Pin Functions (continued)

| PIN | | | MAXIMUM | |
|--------|-----|------|-----------------|--|
| NAME | NO. | TYPE | RATING | DESCRIPTION |
| ENABLE | 23 | I | -0.3 V to 40 V | Enable input |
| FAULT | 36 | 0 | -0.3 V to 6 V | Diagnosis output |
| GND | 29 | I | -0.3 V to 0.3 V | GND |
| NGND | 48 | I | -0.3 V to 0.3 V | Power GND |
| PDCPV | 43 | 0 | -0.3 V to 40 V | Charge pump output |
| PH1M | 27 | 1 | -1 V to 40 V | Phase comparator input |
| PH2M | 26 | I | -1 V to 40 V | Phase comparator input |
| PH3M | 25 | I | -1 V to 40 V | Phase comparator input |
| PHTM | 28 | I | -1 V to 40 V | Phase comparator reference input |
| PMV1 | 22 | 0 | -0.3 V to 6 V | Phase comparator output |
| PMV2 | 21 | 0 | -0.3 V to 6 V | Phase comparator output |
| PMV3 | 20 | 0 | -0.3 V to 6 V | Phase comparator output |
| PRN | 35 | I | -0.3 V to 6 V | Watchdog timer-pulse input |
| RES | 24 | 0 | -0.3 V to 6 V | MCU reset output |
| SCK | 33 | I | -0.3 V to 6 V | SPI clock |
| TEST | 2 | 1 | -0.3 V to 20 V | TEST input |
| UH | 42 | 0 | −5 V to 40 V | Pre-driver output |
| UHS | 41 | 0 | −5 V to 40 V | Pre-driver reference |
| UL | 6 | 0 | –0.3 V to 20 V | Pre-driver output |
| VB | 1 | 1 | -0.3 V to 40 V | VB input |
| VCC | 12 | 1 | -0.3 V to 6 V | VCC supply input |
| VCCB | 13 | 0 | -0.3 V to 40 V | VCC regulator base driver of PNP external transistor |
| VCFB | 14 | 1 | –0.3 V to 40 V | VCC regulator current-sense input |
| VDD | 31 | 0 | -0.3 V to 3.6 V | VDD supply output |
| VH | 40 | 0 | –5 V to 40 V | Pre-driver output |
| VHS | 39 | 0 | –5 V to 40 V | Pre-driver reference |
| VL | 7 | 0 | -0.3 V to 20 V | Pre-driver output |
| WH | 38 | 0 | –5 V to 40 V | Pre-driver output |
| WHS | 37 | 0 | –5 V to 40 V | Pre-driver reference |
| WL | 8 | 0 | -0.3 V to 20 V | Pre-driver output |

6 Specifications

6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)

| | | MIN | MAX | UNIT |
|------------------|-----------------------------|-----|-----|------|
| T_A | Operating temperature range | -40 | 150 | °C |
| T_{J} | Junction temperature | -40 | 175 | ô |
| T _{stg} | Storage temperature | -55 | 175 | °C |

6.2 ESD Ratings

| | | | VALUE | UNIT |
|--------------------|--|----------------------------|-------|------|
| \/ | Electrostatic discharge ⁽¹⁾ | Human-body model (HBM) | ±2000 | |
| V _(ESD) | Electrostatic discharge (*) | Charged-device model (CDM) | ±500 | V |

(1) Performance of ESD testing is according to the ACE-Q100 standard.

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6.3 Thermal Information

| | | DRV3204E-Q1 | |
|-------------------------|--|-------------|------|
| | THERMAL METRIC ⁽¹⁾ | PHP (HTQFP) | UNIT |
| | | 48 PINS | |
| θ_{JA} | Junction-to-ambient thermal resistance | 26.1 | °C/W |
| θ_{JCtop} | Junction-to-case (top) thermal resistance | 11.5 | °C/W |
| θ_{JB} | Junction-to-board thermal resistance | 7.2 | °C/W |
| ΨЈТ | Junction-to-top characterization parameter | 0.2 | °C/W |
| ΨЈВ | Junction-to-board characterization parameter | 7.1 | °C/W |
| θ_{JCbot} | Junction-to-case (bottom) thermal resistance | 0.4 | °C/W |

⁽¹⁾ For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report.

6.4 Electrical Characteristics

VB = 12 V, $T_A = -40$ °C to 150 °C (unless otherwise specified) $^{(1)}$

| | PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|-----------------------|---|---------------------------------------|-----|------|-----|------|
| WATCHDO | G | | | | | |
| VSTN ⁽²⁾ | Function start VCC voltage RES | | | 0.8 | 1.3 | V |
| t _{ON} (2) | Power-on time RES | | 2.5 | 3 | 3.5 | ms |
| t _{OFF} (2) | Clock-off reset time RES | | 64 | 80 | 96 | ms |
| t _{RL} (2) | Reset-pulse low time RES | See Figure 1 | 16 | 20 | 24 | ms |
| t _{RH} (2) | Reset-pulse high time RES | | 64 | 80 | 96 | ms |
| t _{RES} (2) | Reset delay time RES | | 30 | 71.5 | 90 | μs |
| P _{wth} (2) | Pulse duration PRN | | 2 | | | μs |
| SPI | | | | | | |
| f _{op} | SPI clock frequency | | | | 4 | MHz |
| t _{lead} (2) | Enable lead time | | 200 | | | ns |
| t _{wait} (2) | Wait time between two successive communications | | 5 | | | μs |
| t _{lag} (2) | Enable lag time | | 100 | | | ns |
| t _{pw} (2) | SCLK pulse duration | | 100 | | | ns |
| t _{su} (2) | Data setup time | | 100 | | | ns |
| t_h (2) | Data hold time | | 100 | | | ns |
| t _{dis} (2) | Data-output disable time | | | | 200 | ns |
| t _{en} (2) | Data-output enable time | | | | 100 | ns |
| t _d (2) | Data delay time, SCK to DOUT | C _L = 50 pF, see Figure 2. | 0 | | 100 | ns |

¹⁾ The timing parameters are invalid if watch dog timer is disabled.

⁽²⁾ Specified by design.

TEXAS INSTRUMENTS

Electrical Characteristics (continued)

VB = 12 V, $T_A = -40$ °C to 150°C (unless otherwise specified)⁽¹⁾

| | PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|---------------------------------|---|--|----------|-----------|--------------|------|
| CHARGE PU | JMP | | | | <u> </u> | |
| Vchv1_0 | Output voltage, PDCPV | VB = 5.3 V, Iload = 0 mA, C1 = C2 = 47 nF, CCP = 2.2 μ F, R1 = R2 = 0 Ω | VB + 7 | VB + 8 | | V |
| Vchv1_1 | Output voltage, PDCPV | VB = 5.3 V, load = 5 mA, C1 = C2 = 47 nF, CCP = 2.2 μ F, R1 = R2 = 0 Ω | VB + 5.5 | VB + 6.5 | | V |
| Vchv1_2 | Output voltage, PDCPV | VB = 5.3 V, load = 8 mA, C1 = C2 = 47 nF, CCP = 2.2 μ F, R1 = R2 = 0 Ω | VB + 4.5 | VB + 5.5 | | V |
| Vchv2_0 | Output voltage, PDCPV | VB = 12 V, load = 0 mA, C1 = C2 = 47 nF, CCP = 2.2 μ F, R1 = R2 = 0 Ω | VB + 10 | VB + 12 | VB + 14 | V |
| Vchv2_1 | Output voltage, PDCPV | VB = 12 V, load = 11 mA, C1 = C2 = 47 nF, CCP = 2.2 μ F, R1 = R2 = 0 Ω | VB + 9.5 | VB + 11.5 | VB + 13.5 | V |
| Vchv2_2 | Output voltage, PDCPV | VB = 12 V, load = 18 mA, C1 = C2 = 47 nF, CCP = 2.2 μ F, R1 = R2 = 0 Ω | VB + 9 | VB + 11 | VB + 13 | V |
| Vchv3_0 | Output voltage, PDCPV | VB = 18 V, load = 0 mA, C1 = C2 = 47 nF, CCP = 2.2 μ F, R1 = R2 = 0 Ω | VB + 10 | VB + 12 | VB + 14 | V |
| Vchv3_1 | Output voltage, PDCPV | VB = 18 V, load = 13 mA, C1 = C2 = 47 nF, CCP = 2.2 μ F, R1 = R2 = 0 Ω | VB + 10 | VB + 12 | VB + 14 | V |
| Vchv3_2 | Output voltage, PDCPV | VB = 18 V, load = 22 mA, C1 = C2 = 47 nF, CCP = 2.2 μ F, R1 = R2 = 0 Ω | VB + 10 | VB + 12 | VB + 14 | V |
| VchvOV | Overvoltage detection threshold | | 35 | 37.5 | 40 | V |
| VchvUV | Undervoltage detection threshold | | VB + 4 | VB + 4.5 | VB + 5 | V |
| t _{chv} ⁽²⁾ | Rise time | VB = 5.3 V, C1 = C2 = 47 nF, CCP = 2.2 μ F, R1 = R2 = 0 Ω , Vchv, UV released | | 1 | 2 | ms |
| Ron | On-resistance, S1-S4 | See Figure 10 | | 8 | | Ω |
| HIGH-SIDE | PRE-DRIVER | | | | · | |
| VOH_H | Output voltage, turnon side | Isink = 10 mA, PDCPV - xH | | 1.35 | 2.7 | V |
| VOL_H | Output voltage, turnoff side | Isource = 10 mA, xH - xHS | | 25 | 50 | mV |
| RONH_HP | On-resistance, turnon side (Pch) | U(V/W)H = PDCPV - 1 V | | 135 | 300 | Ω |
| RONH_HN | On-resistance, turnon side (Nch) | U(V/W)H = PDCPV - 2.5 V | | 4 | 8 | Ω |
| RONL_H | On-resistance turnoff side | | | 2.5 | 5 | Ω |
| t _{on_h} (2) | Turnon time | C_L = 12 nF, R_L = 0 Ω from 20% to 80% | 50 | | 200 | ns |
| t _{off_h} (2) | Turnoff time | C_L = 12 nF, R_L = 0 Ω from 80% to 20% | 50 | | 200 | ns |
| t _{h-ondly} (2) | Output delay time | C_L = 12 nF, R_L = 0 Ω to 20%, no dead time | | 200 | | ns |
| t _{h-offdly} (2) | Output delay time | C_L = 12 nF, R_L = 0 Ω to 80%, no dead time | | 200 | | ns |
| VGS_hs | Gate-source high -side voltage difference | xH-xHS | -0.3 | | 18 | V |
| LOW-SIDE F | PRE-DRIVER | | | | | |
| VOH_L1 | Output voltage, turnon side | VB = 12 V, Isink = 10 mA, xL - NGND | 10 | 12 | 14 | V |
| VOH_L2 | Output voltage, turnon side | VB = 5.3 V, $Isink = 10 mA$, $xL - NGND$ | 5.5 | 7.5 | 10 | V |
| VOL_L | Output voltage, turnoff side | Isource = 10 mA, xL - NGND | | 25 | 60 | mV |
| RONH_L | On-resistance, turnon side | | | 6 | 12 | Ω |
| RONL_L | On-resistance, turnoff side | | | 2.5 | 6 | Ω |
| t _{on_l} (2) | Turnon time | C_L = 18 nF, R_L = 0 Ω , from 20% to 80% of 12 V, from 20% to 80% of 6 V (VB = 5.3 V) | 50 | | 200 | ns |

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Electrical Characteristics (continued)

VB = 12 V, $T_A = -40$ °C to 150°C (unless otherwise specified)⁽¹⁾

| | PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|----------------------------------|---|--|----------------------|-----------------------------|--------------------------|------|
| $t_{\rm off_I}^{~(2)}$ | Turnoff time | C_L = 18 nF, R_L = 0 Ω , from 80% to 20% of 12 V, from 80% to 20% of 6 V (VB = 5.3 V) | 50 | | 200 | ns |
| t _{l-ondly} (2) | Output delay time | C_L = 18 nF, R_L = 0 Ω , to 20% of 12 V, to 20% of V _{OH} = 6 V (VB = 5.3 V), no dead time | | 200 | | ns |
| t _{l-offdly} (2) | Output delay time | C_L = 18 nF, R_L = 0 $\Omega,$ to 80% of 12 V, to 80% of V $_{OH}$ = 6 V (VB = 5.3 V), no dead time | | 200 | | ns |
| t _{diff1} (2) | Differential time1 | (Th-on) - (Tl-off), no dead time, See Figure 3 | -200 | 0 | 200 | ns |
| t _{diff2} (2) | Differential time2 | (Tl-on) - (Tl-off), no dead time, See Figure 3 | -200 | 0 | 200 | ns |
| t _{dead} ⁽²⁾ | Dead time | OSC1 = 10 MHz SPI register PDCFG.DEADT | 2 1.5 1 0.5 | | 2.2 1.7 1.2 0.7 | μs |
| PHASE CON | MPARTOR | 1 | | | | |
| Viofs | Input offset voltage | | -15 | | 15 | mV |
| Vinm | Input voltage range, PHTM | | 1.3 | | 4.5 | V |
| Vinp | Input voltage range, PHxM | | -1 | 0 | VB | V |
| \ // ₁ | There is a lab become a large transport | ODL STATE ODADE OF LOOMB LIVE | 12.5 | 25 | 50 | mV |
| Vhys | Threshold hysteresis voltage | SPI register SPARE. SEL_COMP_HYS | 25 | 50 | 100 | |
| | | | 50 | 100 | 200 | |
| V _{OH} | Output high voltage | Isink = 2.5 mA | 0.9 × VCC | | | V |
| V _{OL} | Output low voltage | Isource = 2.5 mA | | | 0.1 × VCC | V |
| t _{res_tr} (2) | Response time, rising | C _L = 100 pF | | 0.7 | 1.5 | μs |
| t _{res_tf} (2) | Response time, falling | C _L = 100 pF | | 0.7 | 1.5 | μs |
| MOTOR CUI | RRENT SENSE | | | | | |
| VOfs | Input offset voltage | | - 5 | | 5 | mV |
| VO_0 | Output voltage, ALV | Imotor = 0 A, SPI register CSCFG. CSOFFSET | | 0.5 1 1.5 2 2.5 | | V |
| VLine | Linearity, ALV | Rshunt = 1 m Ω , R11 = R12 = 1 k Ω , R21 = R22 = 30 k Ω | 29.4 | 30 | 30.6 | mV/A |
| VGain | Gain | | 10 | 30 | | V/V |
| Tset_TR1 (2) | Settling time (rise), ALV ±1% | Rshunt = 1 m Ω , VGain = 30, C _L = 100 pF, Imotor = 0 A \rightarrow 30 A, (ALV: 1 V \rightarrow 1.9 V, AREF = 1 V) | | 1 | 2.5 | μs |
| Tset_TR2 ⁽²⁾ | Settling time(rise), ALV ±1% | Rshunt = 1 m Ω , VGain = 30, C _L = 100 pF, Imotor = 0 A \rightarrow 100 A, (ALV: 1 V \rightarrow 4 V, AREF = 1 V) | | 1 | 2.5 | μs |
| Tset_TF1 (2) | Settling time(fall), ALV ±1% | Rshunt = 1 m Ω , VGain = 30, C $_L$ = 100 pF, Imotor = 30 A \rightarrow 0, (ALV: 1.9 V \rightarrow 1 V, AREF = 1 V) | | 1 | 2.5 | μs |
| Tset_TF2 ⁽²⁾ | Settling time(fall), ALV ±1% | Rshunt = 1 m Ω , VGain = 30, C _L = 100 pF, Imotor = 100 A \rightarrow 0, (ALV: 0.4 V \rightarrow 1 V, AREF = 1 V) | | 1 | 2.5 | μs |

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Electrical Characteristics (continued)

VB = 12 V, $T_A = -40$ °C to 150°C (unless otherwise specified)⁽¹⁾

| | PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|------------------------------|--|---|------------------------------|----------------------------|------------------------------|------|
| OVADth | Overcurrent threshold | Rshunt = 1 m Ω , VGain = 30, AREF = 1 V, ADTH = 2.5 V, SPI register FLTCFG. MTOCTH, OVADth = (2 × ADTH - AREF) / (Rshunt × VGain) | 119.7 | 133 | 146.3 | Α |
| TDEL_OVA D ⁽²⁾ | Propagation delay (rise or fall) | | | | 1.5 | μs |
| tfiltMTOC | filtering time | OSC1 = 9 MHz-11 MHz | 0.8 | 1 | 1.2 | μs |
| VCC | | | | | | |
| VCC1 | Output Voltage | | 4.9 | 5 | 5.1 | V |
| VCC2 | Output Voltage | VB = 4.5 V, ILVCC = 5 mA - 150 mA | 4.25 | | 4.5 | V |
| IBVCC | Base Current | | 1.5 | | | mA |
| hfePNP | DC current gain of external PNP | | 100 | | | |
| VLRVCC | Load regulation | ILVCC = 5 mA - 150 mA | -20 | | 20 | mV |
| CVCC | External Capacitance | | 22 | | 100 | μF |
| RVCC | ESR of external Capacitor | | | | 300 | mΩ |
| VCCUV | Under voltage detection threshold | SPI register FLTCFG. VCCUVTH | 3.7 3.9 | 4 4.2 | 4.3 4.5 | V |
| VCCUVHY S | Under voltage detection threshold hysteresis | | 50 | 100 | 200 | mV |
| VCCOV | Overvoltage detection threshold | | 6 | 6.5 | 7 | V |
| VCCOC | Current Limit | Rsns = 0.51 Ω , 0.2 V = Rsns ⁽³⁾ , VCCOC | 300 | 400 | 550 | mA |
| Tvcc1 ⁽²⁾ | Rise Time | VCC > VCCUV, CVCC = 22 μF | | | 0.5 | ms |
| Tvcc2 ⁽²⁾ | Rise Time | VCC > VCCUV, CVCC = 100 μF | | | 1.5 | ms |
| VDD | | | | | | |
| VDD | Output Voltage | | 3 | 3.3 | 3.6 | V |
| CVDD | Load Capacitance | | | 1 | | μF |
| VDDUV | Under voltage detection threshold | | 2.1 | 2.3 | 2.5 | V |
| VDDOV | Overvoltage detection threshold | | 4 | 4.3 | 4.6 | V |
| Tvdd ⁽²⁾ | Rise Time | VDD > VDDUV, CVDD = 1 μF | | | 100 | μs |
| VB MONITO | R | | | | | |
| VBOV | VB overvoltage detection threshold level | | 26.5 | 27.5 | 28.5 | V |
| VBOVhys ⁽²⁾ | VB overvoltage detection hysteresis | | 0.2 | 0.5 | 1.2 | V |
| VBUV | VB Undervoltage detection threshold level | SPI register FLTCFG. VBUVTH | 3.65 4.15 4.65 5.15 | 4 4.5 5 5.5 | 4.35 4.85 5.35 5.85 | V |
| VBUVhys ⁽²⁾ | VB Undervoltage detection hysteresis | SPI register FLTCFG. VBUVTH | 0.1 0.2 0.2 0.3 | 0.25 0.4 0.5 0.65 | 0.5 0.8 1.0 1.3 | V |
| THERMAL S | SHUT DOWN | | | | | |
| TSD ⁽²⁾ | Thermal shut down threshold level | | 155 | 175 | 195 | °C |
| TSDhys ⁽²⁾ | Thermal shut down hysteresis | | 5 | 10 | 15 | °C |

⁽³⁾ No variation of the external components.

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Electrical Characteristics (continued)

VB = 12 V, $T_A = -40$ °C to 150°C (unless otherwise specified)⁽¹⁾

| | PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|-----------------|-------------------------------------|------------------|--------------|-----|--------------|------|
| OSCILLAT | OR | | 1 | | | |
| OSC1 | OSC1 frequency | | 9 | 10 | 11 | MHz |
| OSC2 | OSC2 frequency | | | 10 | | MHz |
| INPUT BUF | FER1 | | | | | |
| V _{IH} | Input threshold logic high | | 0.7 × VCC | | | V |
| V_{IL} | Input threshold logic low | | | | 0.3 × VCC | V |
| Ru or Rd | Input pullup or pulldown resistance | | 50 | 100 | 150 | kΩ |
| OUTPUT B | UFFER1(2) | | | | | |
| V_{OH} | Output level logic high | Isink = 2.5 mA | 0.9 × VCC | | | V |
| V _{OL} | Output level logic low | Isource = 2.5 mA | | | 0.1 × VCC | V |
| OUTPUT B | UFFER3 | · | | | | |
| R_RES | Pullup Resistor | | 2 | 3 | 4 | kΩ |
| V _{OL} | Output level logic low | Isource = 2 mA | | | 0.1 × VCC | V |

6.5 Supply Voltage and Current

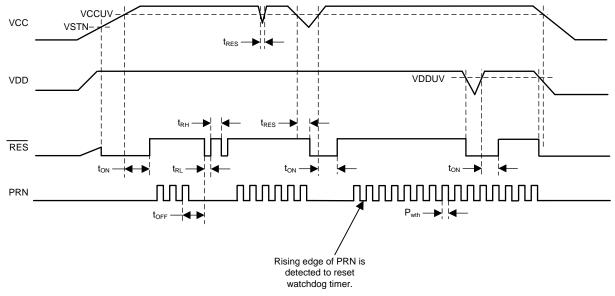
VB = 12 V, $T_A = -40$ °C to 150°C (unless otherwise specified)

| | , n , | . , | | | | |
|--------------------|-------------------------------------|-----------------------|-----|-----|------|------|
| | PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
| SUPPLY | (INPUT | | | | | |
| VB1 ⁽¹⁾ | VB supply voltage (motor operation) | | 5.3 | 12 | 18 | V |
| VB2 ⁽¹⁾ | VB supply voltage (MCU operation) | | 4.5 | 12 | 18 | V |
| VB3 ⁽²⁾ | VB supply voltage | | 18 | | 26.5 | V |
| lvb | VB operating current | ENABLE = High, no PWM | | 18 | 27 | mA |
| lvbq | VB quiescent current | ENABLE = Low | | 50 | 100 | μΑ |

⁽¹⁾ Performance of supply voltage 5.3 V to 18 V is according to the ACE-Q100 (Grade 0) standard.

⁽²⁾ Specified by design.





NOTE: VCC undervoltage condition sets \overline{RES} = Low.

Figure 1. Watchdog Timing Chart

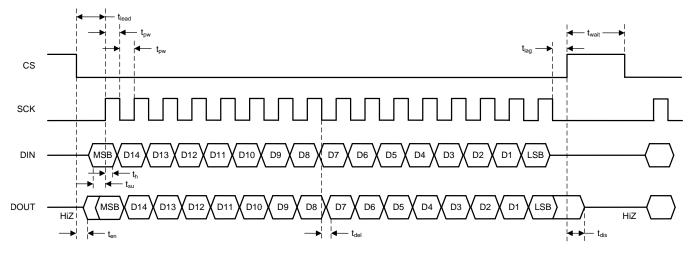
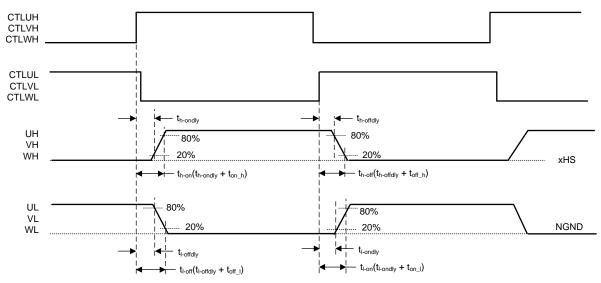


Figure 2. SPI Timing Diagram

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NOTE: This diagram excludes dead time to explain the timing parameters of the pre-driver.

Figure 3. Delay Time From Input to Output

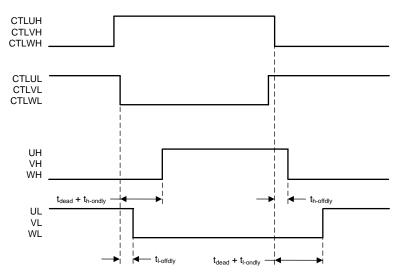


Figure 4. Dead Time

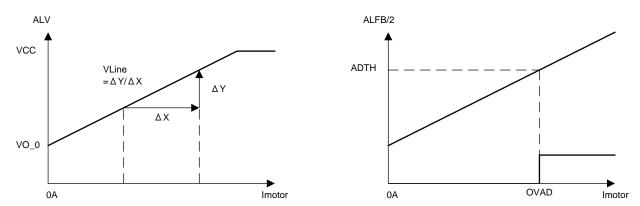
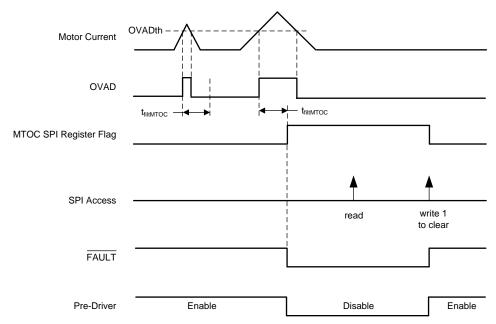


Figure 5. Motor-Current Sense and Overcurrent

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- (1) MCU must set the FLTCFG.FLGLATCH_EN bit to 1 to get the latch-type operation shown in Figure 6.
- (2) When MTOC condition is detected, FAULT is asserted to low if FE_MTOC bit is 1.
- (3) When MTOC condition is detected, Pre Driver is disabled if SE_MTOC is 1.

Figure 6. Motor Overcurrent Event

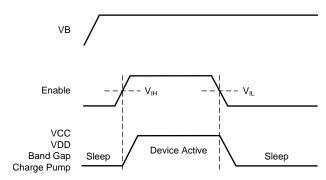
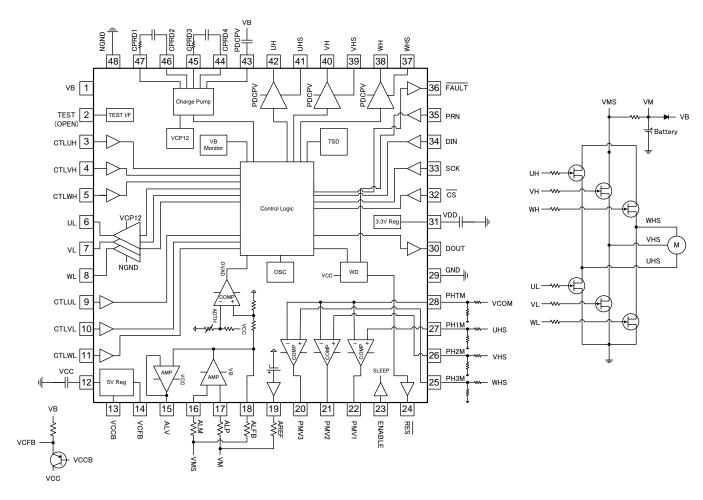


Figure 7. I/O ENABLE Timing Chart



7 Detailed Description

7.1 Functional Block Diagram



7.2 Feature Description

7.2.1 Watchdog

A watchdog monitors the PRN signal and VCC supply level and generates a reset to the MCU via the RES pin if the status of PRN is not normal or VCC is lower than the specified threshold level. Detection of a special pattern on the PRN input during power up can disable the watchdog.



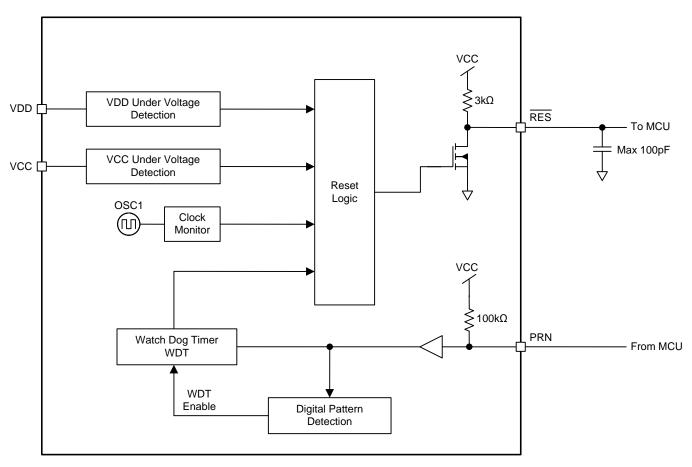


Figure 8. Watchdog Block Diagram

7.2.2 Serial Port I/F

The device configuration is set and the diagnostic information read-out ocurrs through SPI. SPI operates in slave mode. SPI uses four signals according as shown in the timing diagram of Figure 2.

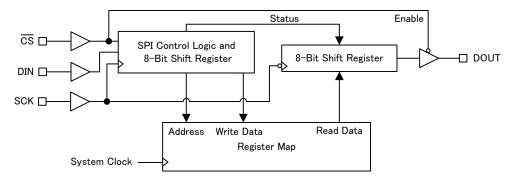


Figure 9. Block Diagram of SPI

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Feature Description (continued)

The MCU uses \overline{CS} to select the IC. \overline{CS} is normally high, and communication is possible only when \overline{CS} is forced low. When \overline{CS} falls, communication between this IC and the MCU starts. The transmitted data are latched and the DOUT output pin comes out of high impedance. When \overline{CS} rises, communication stops. The DOUT output pin goes into high impedance. The next falling edge starts another communication. There is a minimum waiting time between two communications (t_{wait}). The pin has an internal pullup.

7.2.2.2 SCK - Synchronization Serial Clock

The MCU uses SCK to synchronize communication. SCK is normally low, and the valid clock-pulse number is 16. At each falling edge, the MCU writes a new bit on the DIN input, and the IC writes a new bit on the DOUT output pin. At each rising edge, the IC reads the new bit on DIN, and the MCU reads the new bit on DOUT. The maximum clock frequency is 4 MHz. The pin has an internal pulldown.

7.2.2.3 DIN - Serial Input Data

DIN receives 16-bit data. The order of received bits is from the MSB (first) to the LSB (last). The pin has an internal pulldown. Update of the internal register with the received bits occurs only if the number of clock pulses is 16 while $\overline{\text{CS}}$ is low.

7.2.2.4 DOUT - Serial Output Data

DOUT transmits 16-bit data. DOUT is a three-state output, and is in the high-impedance state when $\overline{\text{CS}}$ is high. The order of serial data-bit transmission is from the MSB (first) to the LSB (last).



7.2.3 Charge Pump

The charge-pump block generates a supply for the high-side and low-side pre-drivers to maintain the gate voltage on the external FETs. Use of an external storage capacitor (CCP) and bucket capacitors (C1, C2) supports pre-driver slope and switching-frequency requirements. R1 and R2 can reduce switching current if required. The charge pump has voltage-supervisor functions such as overvoltage and undervoltage, and selectable stop conditions for pre-drivers.

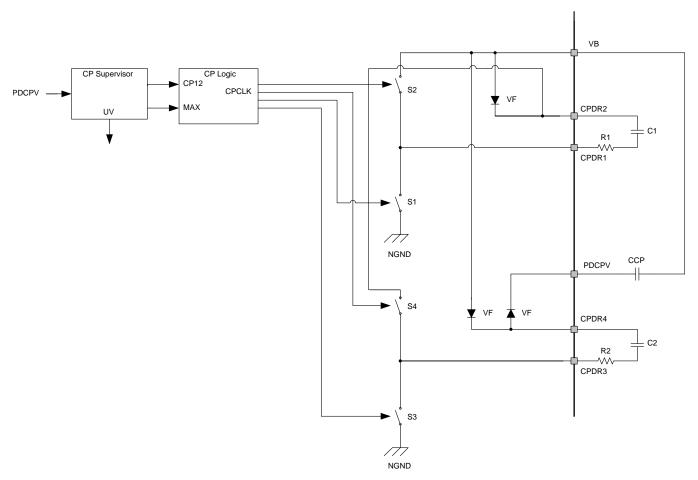


Figure 10. Charge-Pump Block Diagram

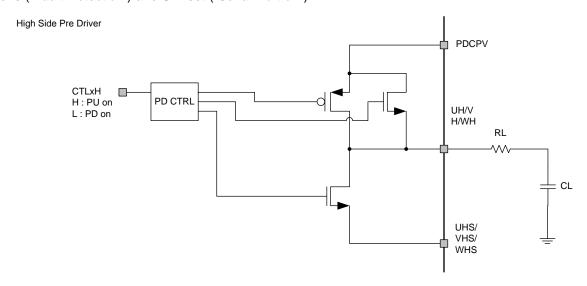


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Feature Description (continued)

7.2.4 Pre-Driver

The pre-driver block provides three high-side pre-drivers and three low-side pre-drivers to drive external N-channel MOSFETs. The turnon side of the high-side pre-drivers supplies the large N-channel transistor current for quick charge, and PMOS supports output voltages up to PDCPV. The turnoff side of the high-side pre-drivers supplies the large N-channel transistor current for quick discharge. The low-side pre-drivers supply the large N-channel transistor current for charge and discharge. VCP12 (created by a charge pump) controls the output voltage of the low-side pre-driver to output less than 18 V. The pre-driver has a stop condition in some fault conditions (Fault Detection) and SPI set (Serial Port I/F).



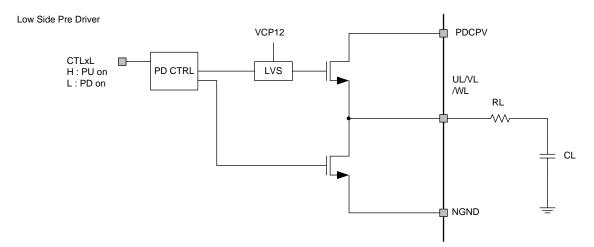


Figure 11. Pre-Driver Block Diagram

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7.2.5 Phase Comparator

The three-channel comparator module monitors the external FETs by detecting the drain-source voltage across the high-side and low-side FETs. PHTM is the threshold level of the comparators usable for sensorless communication. Figure 12 shows an example of the threshold level.

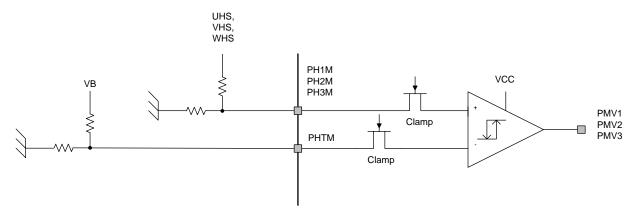


Figure 12. Phase Comparator Block Diagram

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Feature Description (continued)

7.2.6 Motor-Current Sense

The operational amplifier operates with an external resistor network for higher flexibility to adjust the current measurement to application requirements. The first-stage amplifier is operating with the external resistor and the output voltage up to VB at ALFB. The gain of amplifier is adjustable by external resistors from ×10 to ×30. The second-stage amplifier is buffer to MCU at ALV. Current sense has comparator for motor overcurrent (OVAD). ADTH is the overcurrent threshold level and set value by SPI. Figure 13 shows the curve of detection level. ALFB is divided by 2 and compare this value with ADTH. In the recommended application, zero-point adjustment is required as large error offset in initial condition.

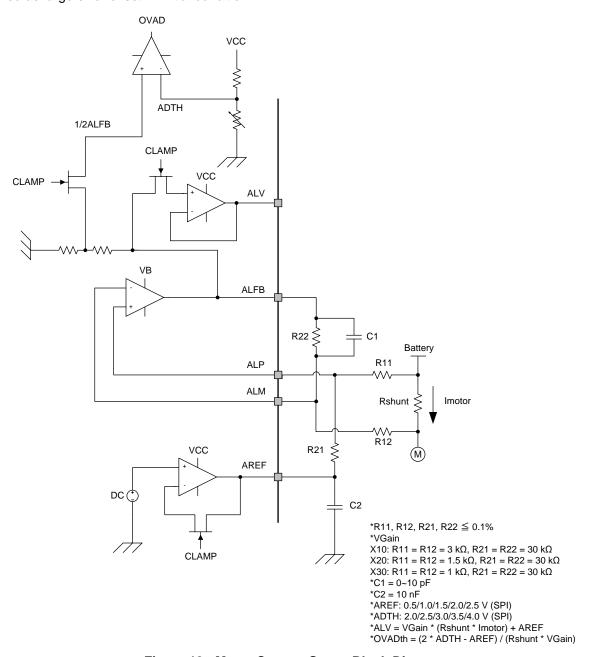


Figure 13. Motor Current-Sense Block Diagram

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7.2.7 Regulators

The regulator block offers a 5-V LDO and a 3.3-V LDO. The VCC LDO regulates VB down to 5 V with an external PNP controlled by the regulator block. The 5 V is supplied to MCU and other components.

The VDD regulator regulates VB down to 3.3 V with internal FET and controller. The 5-V LDO is protected against short to GND fault. Overvoltage and under voltage events of both supplies are detected. The under voltage of the 5-V LDO is set by SPI.

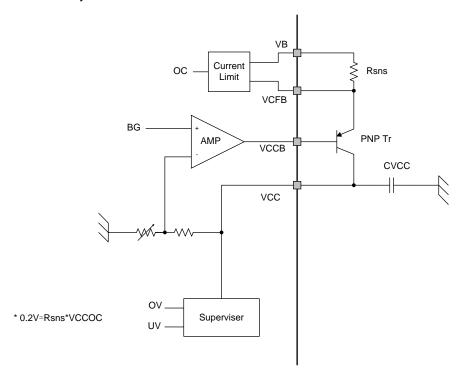


Figure 14. VCC Block Diagram (External Driver)

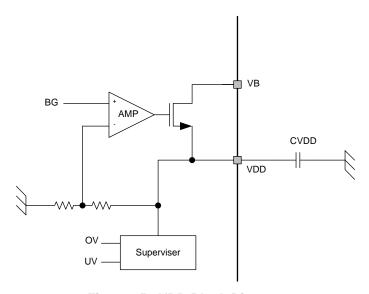


Figure 15. VDD Block Diagram

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7.2.8 VB Monitor

The VB monitoring system has two comparators for undervoltage and overvoltage, and has pre-driver stop controlling system respectively. Overvoltage provides pre-driver stop condition selectable (SPI control). On the other hand, under voltage must stop pre-driver operation under detection (non-selectable). System should return to normal operation automatically after undetected level.

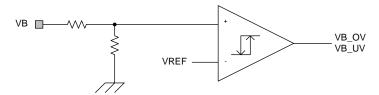


Figure 16. VB Monitor Block Diagram

7.2.9 Thermal Shutdown

The device has temperature sensors that produce pre-driver stop condition if the chip temperature exceeds 175°C (typical).

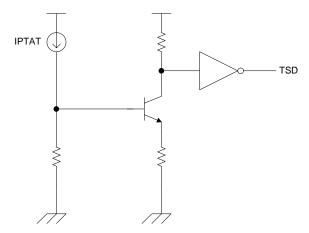


Figure 17. Thermal Shutdown Block Diagram



7.2.10 Oscillator

The oscillator block generates two 10-MHZ clock signals. OSC1 is the primary clock used for internal logic synchronization and timing control. OSC2 is the secondary clock used to monitor the status of OSC1.

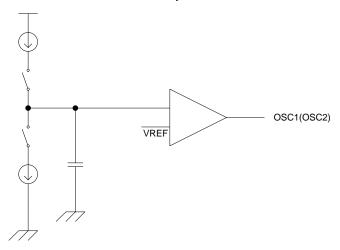
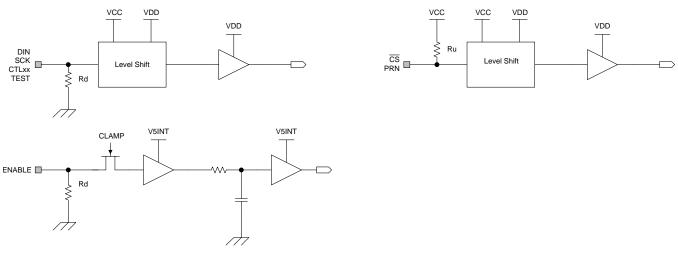


Figure 18. Oscillator Block Diagram

7.2.11 I/O



^{*} V5INT is the internal power supply.

Figure 19. Input Buffer1 Block Diagram

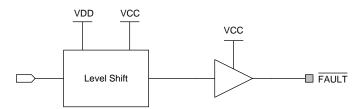


Figure 20. Output Buffer1 Block Diagram



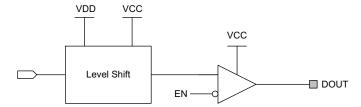


Figure 21. Output Buffer2 Block Diagram

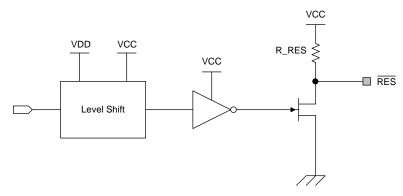


Figure 22. Output Buffer3 Block Diagram

Table 1. Recommended Pin Termination

| PIN NAME | DESCRIPTION | TERMINATION | |
|----------|-----------------|-------------|--|
| TEST | Test mode input | OPEN | |

7.2.12 Fault Detection

Table 2. Fault Detection

| ITEMS | SPI FLTFLG | Pre Driver ⁽¹⁾ | FAULT ⁽²⁾ | RES | Others |
|---------------------|------------|---------------------------|----------------------|-----|--------------------------|
| VB - Overvoltage | VBOV | Disable | L | Н | |
| VB - Undervoltage | VBUV | Disable | L | Н | |
| CP - Overvoltage | CPOV | Disable | L | Н | |
| CP - Undervoltage | CPUV | Disable | L | Н | |
| VCC - Overvoltage | VCCOV | Disable | L | Н | |
| VCC - Under Voltage | - | Disable (3) | Н | L | |
| VCC - Overcurrent | VCCOC | Disable | L | Н | |
| Motor - Overcurrent | MTOC | Disable | L | Н | |
| VDD - Overvoltage | VDDOV | Disable | L | Н | |
| VDD - Undervoltage | - | Disable ⁽³⁾ | Н | L | |
| Thermal shutdown | TSD | Disable | L | Н | |
| Watch Dog | - | - | Н | L | |
| Clock Monitor | - | - | Н | L | |
| SPI format error | - | - | Н | Н | SPI serial out error bit |

- Pre-driver is disabled if the conditions occur and SDNEN register bits are 1.
- FAULT pin is asserted to low if the conditions occur and FLTEN register bits are 1.
- Pre-driver is disabled by VCC undervoltage and VDD undervoltage conditions regardless of SPI register setting.

Product Folder Links: DRV3204E-Q1



7.3 Register Maps

7.3.1 Register Descriptions

Access type: R = Read and W = Write.

Reserved register: Read of reserved bits return 0 and write has no effect.

Table 3. CFGUNLK (Address 0x01): Configuration Unlock Register

| Bit | Name | Туре | Reset | Description |
|-----|---------|------|-------|---|
| 3:0 | CFGUNLK | RW | 0000 | DRV3204E-Q1 SPI register map has lock and unlock mode, and it is in lock mode by default. MCU can write values of the following registers in unlock mode; |
| | | | | • FLTCFG |
| | | | | FLTEN0 and FLTEN1 |
| | | | | SDNEN0 and SDNEN1 |
| | | | | • CSCFG |
| | | | | • PDCFG |
| | | | | • WDCFG |
| | | | | In lock mode, read returns the values, but writing the registers have no effect. |
| | | | | Device enters unlock mode by writing 0x5, 0x8, 0x7 to CFGUNLK register in series. Device exits from unlock mode by writing 0x0. |

Table 4. FLTCFG (Address 0x02): Fault Detection Configuration Register

| Bit | Name | Туре | Reset | Description |
|-----|-------------|------|-------|--|
| 7 | FLGLATCH_EN | RW | 0 | Fault-flag (FLTFLG*) latch enable |
| | | | | 0: Fault events do not latch fault-flag register bits. |
| | | | | 1: Latching of fault-flag register bits by the fault events occurs. The flag bits remain asserted until cleared. |
| 6:4 | мтостн | RW | 000 | Motor overcurrent detection threshold (ADTH) 000: 2 V 001: 2.5 V 010: 3 V 011: 3.5 V 100: 4 V Others: 2 V |
| 3 | RSVD | R | 0 | Reserved |
| 2 | VCCUVTH | RW | 0 | VCC undervoltage detection threshold 0: 4 V 1: 4.2 V |
| 1:0 | VBUVTH | RW | 00 | VB undervoltage detection threshold 00: 4 V 01: 4.5 V 10: 5 V 11: 5.5 V |

Table 5. FLTEN0 (Address 0x04): FAULT Pin Enable Register 0

| Bit | Name | Туре | Reset | Description |
|-----|----------|------|-------|---|
| 7 | FE_MTOC | RW | 1 | FAULT pin enable of FLTFLG0 register bits. |
| 6 | FE_VCCOC | RW | 1 | 0: Assertion of the FAULT pin does not occur when the fault flag bit is 1 |
| 5 | FE_VCCOV | RW | 1 | 1: Assertion of the FAULT pin to low level occurs when the fault flag bit is 1. See Figure 23 |
| 4 | FE_VDDOV | RW | 1 | |
| 3 | FE_CPOV | RW | 1 | |
| 2 | FE_CPUV | RW | 1 | |
| 1 | FE_VBOV | RW | 1 | |
| 0 | FE_VBUV | RW | 1 | |

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Table 6. FLTEN1 (Address 0x05): FAULT Pin Enable Register 1

| Bit | Name | Туре | Reset | Description |
|-----|--------|------|----------|---|
| 7:1 | RSVD | R | 0000 000 | Reserved |
| 0 | FE_TSD | RW | 1 | FAULT pin enable of TSD flag bit |
| | | | | 0: Assertion of the FAULT pin does not occur when the fault flag bit is 1 |
| | | | | 1: Assertion of the FAULT pin to low level occurs when the TSD flag bit is 1. See Figure 23 |

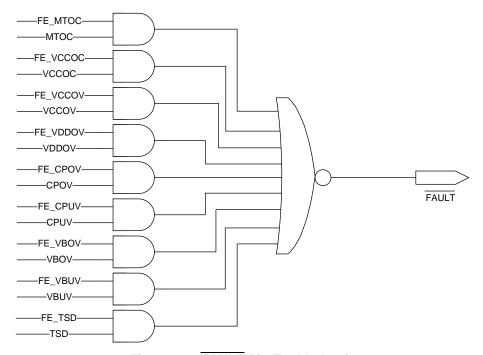


Figure 23. FAULT Pin Enable Logic

Table 7. SDNEN0 (Address 0x06): Pre-Driver Shutdown Enable Register 0

| | | | | · · · · · · · · · · · · · · · · · · · |
|-----|----------|------|-------|--|
| Bit | Name | Туре | Reset | Description |
| 7 | SE_MTOC | RW | 1 | Pre-driver shutdown enable of FLTFLG0 register bits |
| 6 | SE_VCCOC | RW | 1 | 0: Disabling of the pre-driver outputs does not occur when the fault flag bit is 1. |
| 5 | SE_VCCOV | RW | 1 | 1: Disabling of the pre-driver outputs occurs when the fault flag bit is 1. Both the high-side and low-side FETs turn off. |
| 4 | SE_VDDOV | RW | 1 | See Figure 24. |
| 3 | SE_CPOV | RW | 1 | |
| 2 | SE_CPUV | RW | 1 | |
| 1 | SE_VBOV | RW | 1 | |
| 0 | SE_VBUV | RW | 1 | |

Table 8. SDNEN1 (Address 0x07): Pre-Driver Shutdown Enable Register 1

| Bit | Name | Туре | Reset | Description |
|-----|--------|------|----------|--|
| 7:1 | RSVD | R | 0000 000 | Reserved |
| 0 | SE_TSD | RW | 1 | Pre-driver shutdown enable of TSD flag bits 0: Disabling of the pre-driver outputs does not occur when the TSD flag bit is 1. 1: Disabling of the pre-driver outputs occurs when the TSD flag bit is 1. Both the high-side and low-side FETs turn off. See Figure 24. |



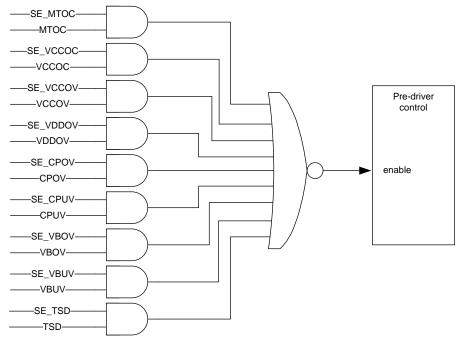


Figure 24. Pre-Driver Shutdown Logic

Table 9. FLTFLG0 (Address 0x08): Fault Flag Register 0

| Bit | Name | Type ⁽¹⁾ | Reset | Description |
|-----|-------|---------------------|-------|---|
| | | | | Fault flag bits of the following conditions; (2) |
| 7 | МТОС | RW | 0 | MTOC: Motor overcurrent. (OVAD) |
| 6 | VCCOC | RW | 0 | VCCOC: VCC overcurrent |
| 5 | VCCOV | RW | 0 | VCCOV: VCC overvoltage |
| 4 | VDDOV | RW | 0 | VDDOV: VDD overvoltage |
| 3 | CPOV | RW | 0 | CPOV: Charge-pump overvoltage |
| 2 | CPUV | RW | 0 | CPUV: Charge-pump undervoltage |
| 1 | VBOV | RW | 0 | VBOV: VB overvoltage |
| 0 | VBUV | RW | 0 | VBUV: VB undervoltage |
| | | | | If FLTCFG.FLGLATCH_EN = 1 |
| | | | | 0: Read = No fault condition exists since last cleared. |
| | | | | Write = No effect |
| | | | | 1: Read = Fault condition exists. |
| | | | | Write = Clear the flag. |
| | | | | If FLTCFG.FLGLATCH_EN = 0 |
| | | | | 0: Read = No fault condition |
| | | | | Write = No effect |
| | | | | 1: Read = Fault condition |
| | | | | Write = No effect |

- (1) R: Read, W: Write
- (2) Assertion of the fault flags may occur during power up.

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Table 10. FLGFLT1 (Address 0x09): Fault Flag Register 1

| Bit | Name | Type ⁽¹⁾ | Reset | Description |
|-----|------|---------------------|-----------|--|
| 7:1 | RSVD | R | 0000 0000 | Reserved |
| 0 | VBUV | RW | 1 | Fault flag bit of thermal shutdown condition. (2) If FLTCFG.FLGLATCH_EN = 1 |
| | | | | 0: Read = No fault condition exists since last cleared. |
| | | | | Write = No effect |
| | | | | 1: Read = Fault condition exists. |
| | | | | Write = Clear the flag |
| | | | | If FLTCFG.FLGLATCH_EN = 0 |
| | | | | 0: Read = No fault condition |
| | | | | Write = No effect |
| | | | | 1: Read = Fault condition |
| | | | | Write = No effect |

- (1) R: Read, W: Write
- (2) Assertion of the fault flags may occur during power up.

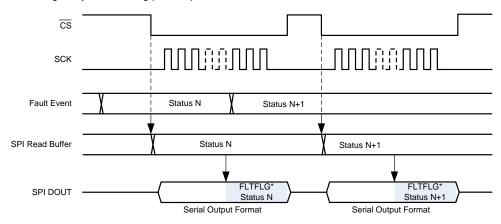
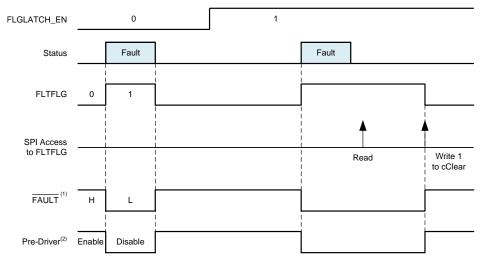


Figure 25. SPI Data-Out Timing Chart of Fault Flag Registers



- (1) Assertion of \overline{FAULT} occurs if FLTEN = 1.
- (2) Disabling of pre-driveroccurs if SDNEN = 1.

Figure 26. FLGFLG and FLGLATCH_EN

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Table 11. CSCFG (Address 0x0A): Current Sense Configuration Register

| Bit | Name | Type ⁽¹⁾ | Reset | Description |
|-----|----------|---------------------|--------|---|
| 7:3 | RSVD | R | 0000 0 | Reserved |
| 2:0 | CSOFFSET | RW | 000 | Current-sense offset 000: 0.5 V 001: 1 V 010: 1.5 V 011: 2 V 100: 2.5 V Others: 0.5 V |

(1) R: Read W: Write

Table 12. PDCFG (Address 0x0B): Pre-Driver Configuration Register

| Bit | Name | Type ⁽¹⁾ | Reset | Description |
|-----|-------|---------------------|---------|--|
| 7:2 | RSVD | R | 0000 00 | Reserved |
| 1:0 | DEADT | RW | 00 | Dead time (= t_{dead}) 00: 2.1 μ s 01: 1.6 μ s 10: 1.1 μ s 11: 0.6 μ s The actual dead time has ±0.1 μ s variation from the typical value. |

(1) R: Read W: Write

Table 13. DIAG (Address 0x0C): Diagnosis Register

| Bit | Name | Туре | Reset | Description | | | | |
|-----|----------|------|--------|---|--|--|--|--|
| 7:3 | RSVD | R | 0000 0 | Reserved | | | | |
| 2 | VCCUVRST | R | 0 | nRES reset source information | | | | |
| 1 | WDTRST | R | 0 | t 2 = VCCUVRST - VCC undervoltage | | | | |
| 0 | CMRST | R | 0 | Bit 1 = WDTRST - watchdog timer | | | | |
| | | | | Bit 0 = CMRST - clock monitor | | | | |
| | | | | 0: Read = Reset has not occurred. | | | | |
| | | | | Write = No effect | | | | |
| | | | | 1: Read = A corresponding reset source caused the last reset condition. | | | | |
| | | | | Write = No effect | | | | |
| | | | | Read access to this register clears the bits. | | | | |

Table 14. SPARE (Address 0x0D): Spare Register

| Bit | Name | Type ⁽¹⁾ | Reset | Description |
|-----|--------------|---------------------|---------|---|
| 7:2 | SPARE | RW | 0000 00 | Spare registers for future use. Read and write have no effect. |
| 1:0 | SEL_COMP_HYS | RW | 00 | Select phase comparator hysteresis voltage. The following show the typical values. 00: 0 V 01: 25 mV 10: 50 mV 11: 100 mV |

(1) R: Read W: Write



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Table 15. SPI Serial Input Format

| | MSB | D14 | D13 | D12 | D11 | D10 | D9 | D8 |
|-----|---------|---------|---------|---------|---------|---------|---------|---------|
| DIN | RW[1] | RW[0] | Addr[5] | Addr[4] | Addr[3] | Addr[2] | Addr[1] | Addr[0] |
| | D7 | D6 | D5 | D4 | D3 | D2 | D1 | LSB |
| DIN | Data[7] | Data[6] | Data[5] | Data[4] | Data[3] | Data[2] | Data[1] | Data[0] |

Table 16. SPI Serial Output Data Format

| | MSB | D14 | D13 | D12 | D11 | D10 | D9 | D8 |
|------|---------|-------------|---------|---------|---------|---------|---------|---------|
| DOUT | 0 | Frame fault | 0 | 0 | 0 | 0 | 0 | 1 |
| | D7 | D6 | D5 | D4 | D3 | D2 | D1 | LSB |
| DOUT | Data[7] | Data[6] | Data[5] | Data[4] | Data[3] | Data[2] | Data[1] | Data[0] |

SPI serial input and output format

RW[1:0] : 01: write mode; 00: read mode

Addr[5:0] : Address of SPI access

Data[7:0] : Input data to write or output data to read
Frame fault : 0: No error exists in the previous SPI frame.

: 1: Error exists in the previous SPI frame.

Table 17. SPI Register Map

| Register Name | Addr (Hex) | b7 | b6 | b5 | b4 | b3 | b2 | b1 | b0 | Reset (Hex) | |
|------------------|---------------|----------------------|---------------|----------|----------|---------|---------|---------|---------|----------------|--|
| Reserved | 00 | | | | RS | VD | • | | | 00 | |
| CFGUNLK | 01 | | RSVE |) | | | CF | GUNLK | | 00 | |
| FLTCFG | 02 | FLGLATCH_EN | | мтостн | | RSVD | VCCUVTH | VBU\ | /TH | 00 | |
| Reserved | 03 | | • | | RS | VD | • | | | 00 | |
| FLTEN0 | 04 | FE_MTOC | FE_VCCOC | FE_VCCOV | FE_VDDOV | FE_CPOV | FE_CPUV | FE_VBOV | FE_VBUV | FF | |
| FLTEN1 | 05 | | | | RSVD | | | | FE_TSD | 01 | |
| SDNEN0 | 06 | SE_MTOC | SE_VCCOC | SE_VCCOV | SE_VDDOV | SE_CPOV | SE_CPUV | SE_VBOV | SE_VBUV | FF | |
| SDNEN1 | 07 | | | | RSVD | 1 | | | SE_TSD | 01 | |
| FLTFLG0 | 08 | MTOC | VCCOC | VCCOV | VDDOV | CPOV | CPUV | VBOV | VBUV | 00 | |
| FLTFLG1 | 09 | | | | RSVD | 1 | | | TSD | 00 | |
| CSCFG | 0A | | RSVD CSOFFSET | | | | | | | | |
| PDCFG | 0B | | DT | 00 | | | | | | | |
| DIAG | 0C | RSVD VCCUVRST WDTRST | | | | | | | | 00 | |
| SPARE | 0D | | MP_HYS | 00 | | | | | | | |
| Reserved | 0E-3F | | | | RS | VD | | | | 00 | |



8 Application and Implementation

NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

8.1 Typical Application

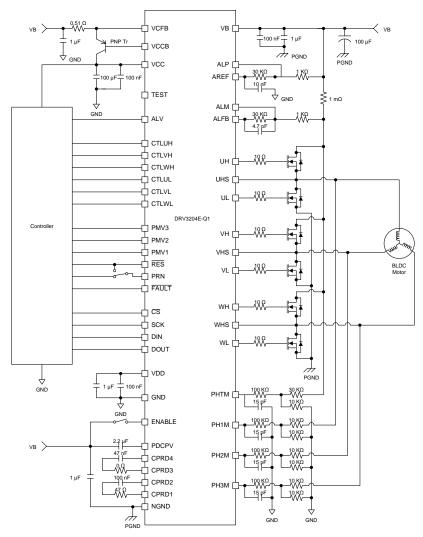


Figure 27. Typical Application Schematic

Submit Documentation Feedback

DRV3204E-Q1

SLVSCB5B - OCTOBER 2013-REVISED JULY 2016

www.ti.com

9 Device and Documentation Support

9.1 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. In the upper right corner, click on *Alert me* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

9.2 Community Resources

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

TI E2E™ Online Community TI's Engineer-to-Engineer (E2E) Community. Created to foster collaboration among engineers. At e2e.ti.com, you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

Design Support *TI's Design Support* Quickly find helpful E2E forums along with design support tools and contact information for technical support.

9.3 Trademarks

E2E is a trademark of Texas Instruments.

All other trademarks are the property of their respective owners.

9.4 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

9.5 Glossary

SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms, and definitions.

10 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.



PACKAGE OPTION ADDENDUM

27-.lun-2016

PACKAGING INFORMATION

| Orderable Device | Status | Package Type | Package Drawing | Pins | Package Qty | Eco Plan | Lead/Ball Finish | MSL Peak Temp | Op Temp (°C) | Device Marking (4/5) | Samples |
|------------------|--------|--------------|--------------------|------|----------------|----------------------------|------------------|---------------------|--------------|----------------------|---------|
| DRV3204EPHPQ1 | NRND | HTQFP | PHP | 48 | 250 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-3-260C-168 HR | -40 to 150 | DRV3204E | |
| DRV3204EPHPRQ1 | NRND | HTQFP | PHP | 48 | 1000 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-3-260C-168 HR | -40 to 150 | DRV3204E | |

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead/Ball Finish Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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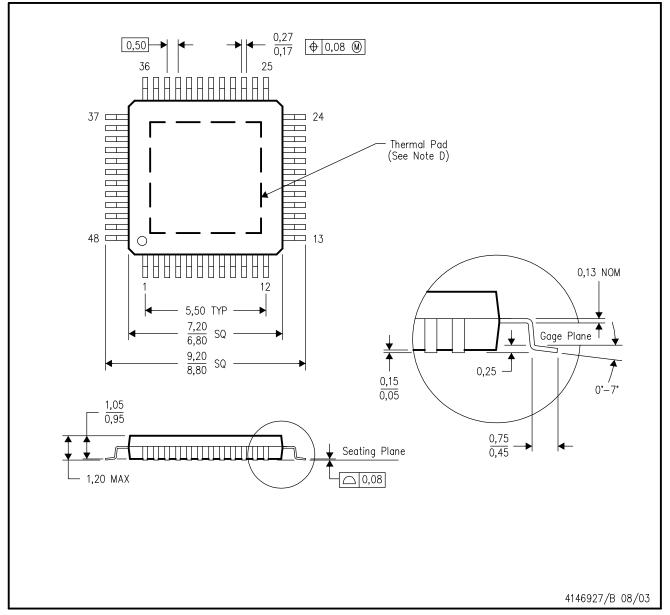
PACKAGE OPTION ADDENDUM

27-Jun-2016

| In no event shall TI's liability arising out of suc | ch information exceed the total purchase price | of the TI part(s) at issue in this document sole | d by TI to Customer on an annual basis. |
|---|--|--|---|
| | | | |
| | | | |

PHP (S-PQFP-G48)

PowerPAD™ PLASTIC QUAD FLATPACK



NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion
- D. This package is designed to be soldered to a thermal pad on the board. Refer to Technical Brief, PowerPad Thermally Enhanced Package, Texas Instruments Literature No. SLMA002 for information regarding recommended board layout. This document is available at www.ti.com www.ti.com.
- E. Falls within JEDEC MS-026

PowerPAD is a trademark of Texas Instruments.



PHP (S-PQFP-G48)

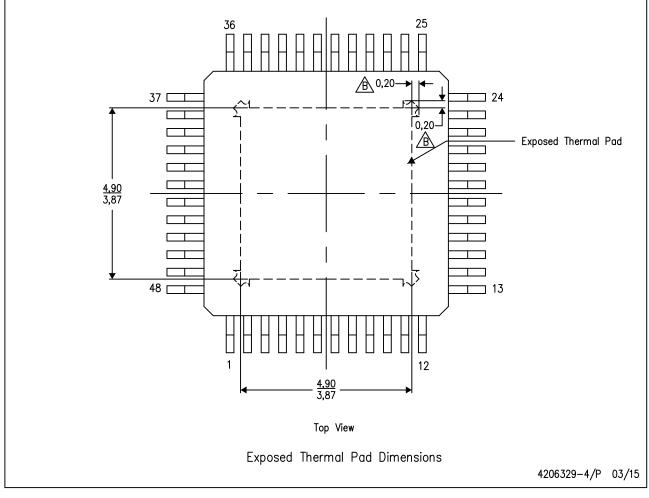
PowerPAD™ PLASTIC QUAD FLATPACK

THERMAL INFORMATION

This PowerPAD $^{\mathbf{m}}$ package incorporates an exposed thermal pad that is designed to be attached to a printed circuit board (PCB). The thermal pad must be soldered directly to the PCB. After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For additional information on the PowerPAD package and how to take advantage of its heat dissipating abilities, refer to Technical Brief, PowerPAD Thermally Enhanced Package, Texas Instruments Literature No. SLMA002 and Application Brief, PowerPAD Made Easy, Texas Instruments Literature No. SLMA004. Both documents are available at www.ti.com.

The exposed thermal pad dimensions for this package are shown in the following illustration.



NOTE: A. All linear dimensions are in millimeters

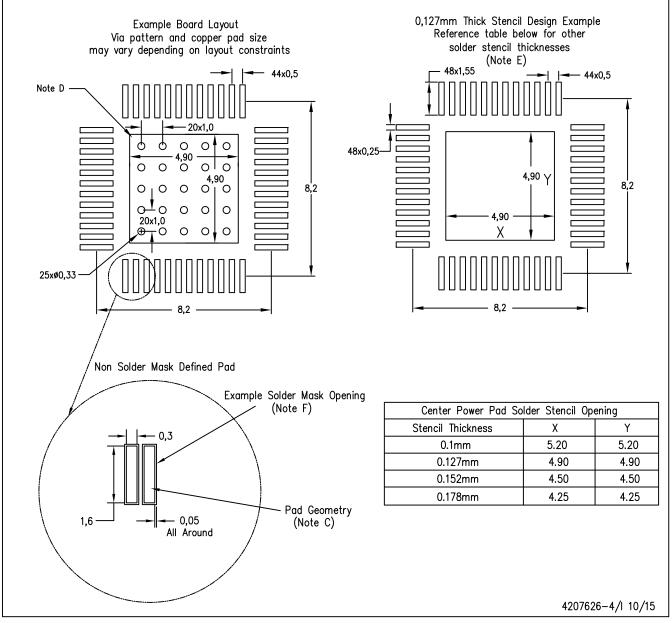
B Tie strap features may not be present.

PowerPAD is a trademark of Texas Instruments



PHP (S-PQFP-G48)

PowerPAD™ PLASTIC QUAD FLATPACK



NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. This package is designed to be soldered to a thermal pad on the board. Refer to Technical Brief, PowerPad Thermally Enhanced Package, Texas Instruments Literature No. SLMA002, SLMA004, and also the Product Data Sheets for specific thermal information, via requirements, and recommended board layout. These documents are available at www.ti.com http://www.ti.com.
- E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC 7525 for stencil design considerations.
- F. Customers should contact their board fabrication site for recommended solder mask tolerances and via tenting options for vias placed in the thermal pad.

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